DESIGN CONSIDERATIONS AM TRANSMITTERS



Overview

Design Criteria Modulation **TX Block Diagram RF** Amplifier Harmonic Filter Combiner Modulator Exciter

Power Supply Circuit Board Cooling Protection



Early conceptual design starts with knowing a desired RF output power and knowing the Regulatory Requirement governing the broadcast signal such as:

- CE RED
- FCC CFR47 Part 73
- Innovation, Science and Economic Development Canada BETS5

These regulations govern items such as occupied bandwidth, spurious and harmonic emissions, Audio quality, AM noise, FM noise, Electromagnetic compatibility, safety.



Other design considerations include:

- Reliability
- Redundancy
- Dollars per watt (\$/W)
- Power density (W/in³)
- Power conversion efficiency (operating cost)
- Feature set

These considerations can quite often conflict with each other such as redundancy and \$/W.

Designers must understand and choose their guiding principals



Nautel has always considered reliability one of the leading design principal and as such has an internal engineering document guiding our acceptable component stress.

Electrical stress, at its essence comes from two parameters:

- Voltage (Joules/coulomb) stress causing dielectric breakdown and dielectric heating
- Current (Coulombs/second) stress causing excessive heating of conductors ($P = i^2 R$)



Examples of Nautel design guidelines include:

- Resistors not to dissipate more than 50% of manufactures rating
- Capacitors operating voltage to be 66% of rating
- Voltage stress in air to be 5 V/mil (breakdown at sea level occurs at 75 V/mil in a uniform field)
- Transistor junction temperature not to exceed 75% of max rating under normal operating conditions

These guidelines have helped establish a history of highly reliable transmitters.



Reliability and redundancy have also greatly influence Nautel designs. Going back to our roots, it was a request for improved MTBF that drove the first solid state designs as the Canadian Coast Guard needed ultra reliable transmitters in northern Canada which tube designs of the day could not meet.



We continue to build the majority of our design redundancy in mind including:

- multiple parallel amplifiers that can be hot serviced
- dual exciters
- dual low voltage power supplies
- Multiple parallel cooling fans



Association Connecting Electronics Industries IPC IPC STANDARDS -EVERYTHING YOU NEED FROM START TO FINISH End-Product Advanced Packaging SMT Reliability IPC J-STD-030 Acceptability Standard for IPC-9701-IPC-9704 IPC-7092 Manufacture, Inspection, & Testing IPC-9706-IPC-9709 IPC-7093 of Electronic Enclosures **IPC-7094** IPC-A-630 **IPC-7095** Repair IPC-7711/21 **Requirements and Acceptance for** Storage **Cable and Wire Harness Assemblies** & Handling Solderability IPC-A-620 IPC J-STD-020 IPC J-STD-002 IPC J-STD-033 IPC J-STD-003 IPC J-STD-075 Acceptability of IPC-1601 **Electronic Assemblies** Stencil Design IPC-A-610 Guidelines Test Methods IPC-7525 IPC-TM-650 **Requirements for Soldered** IPC-7526 IPC-9631 Electronic Assemblies IPC-7527 IPC-9691 IPC J-STD-001/IPC-HDBK-001, IPC-AJ-820 **Electrical Test** Assembly IPC-9252 Acceptability of Printed Boards Materials IPC J-STD-004 IPC-A-600 IPC J-STD-005 Surface IPC-HDBK-005 Finishes Qualifications for Printed Boards IPC J-STD-006 **IPC-4552** IPC-6011, 6012, 6013, 6017, 6018 IPC-SM-817 IPC-4553 **IPC-CC-830** IPC-4554 HDBK-830 IPC-4556 Base Materials for Printed Boards **HDBK-850** IPC-4101, 4104, 4202, 4203, & 4204 High Speed/ Frequency Solder Mask IPC-2141 IPC-SM-840 **Design & Land Patterns** IPC-2251 IPC-2221, 2222 & 2223 + 7351 **Copper Foils** Materials IPC-4562 Declaration **Data Transfer and Electronic** IPC-1751 Product Documentation IPC-1752 IPC-2581 Series, IPC-2610 Series IPC-1755 Learn about IPC standards at www.ipc.org/standards DECEMBER 2014

Nautel also uses IPC standards to guide the construction of all electronic assemblies.



Generic Transmitter Block Diagram



- Modulation techniques
 - Linear amplification
 - Single Pulse Duration Modulation (PDM)
 - Bi-Phase Pulse Duration Modulation (PDM)
 - Multi Phase Pulse Duration Modulation (PDM)
 - Pulse Step Modulation
 - Pulse Step Modulation with step interpolation



$$e = (1 + M \sin \omega_m t) \cdot \sin(\omega_c t)$$

Where

M is modulation index sin ω_m t is modulating frequency sin(ω_c t) is the carrier frequency



Consider a carrier wave (sine wave) of frequency f_c and amplitude A given by:

 $c(t) = A \cdot \sin(2\pi f_c t)$

Let m(t) represent the modulation waveform. For this example, we shall take the modulation to be simply a sine wave of a frequency f_m , a much lower frequency (such as an audio frequency) than f_c :

 $m(t) = M \cdot \cos(2\pi f_m t + \phi)$

where *M* is the amplitude of the modulation. We shall insist that M<1 so that (1+m(t)) is always positive. If M>1 then overmodulation occurs and reconstruction of message signal from the transmitted signal would lead in loss of original signal. Amplitude modulation results when the carrier c(t) is multiplied by the positive quantity (1+m(t)):

 $y(t) = [\mathbf{1} + \boldsymbol{m}(t)] \cdot \boldsymbol{c}(t)$

 $= [1 + M \cdot \cos(2\pi f_m t + \phi)] \cdot A \cdot \sin(2\pi f_c t)$



Using trig identities, y(t) can be shown to be the sum of three sine waves:

$$y(t)=A\cdot \sin(2\pi f_c t)+rac{AM}{2}\left[\sin(2\pi (f_c+f_m)t+\phi)+\sin(2\pi (f_c-f_m)t-\phi)
ight].$$

Therefore, the modulated signal has three components: the carrier wave c(t) which is unchanged, and two pure sine waves (known as sidebands) with frequencies slightly above and below the carrier frequency fc.



Envelope Elimination and Restoration a.k.a. Kahn Technique









AM Transmitter Block Diagram





AM Transmitter Block Diagram



The RF amplifier design is critical to the transmitter's \$/W, W/in³, efficiency and reliability.

Usually, the amplifier will be the building block of a family of models.

The power capability needs to be large enough to minimize combiner and connectors costs but small enough not to drastically affect power capability under failure. Shipping and servicing weights are also very important.



Class D amplification has been the topography of choice since the early 1980's. Class D has excellent efficiency (theoretically 100%), good W and W

Choosing the switching device for the full bridge is critical as well.

Drain current, input capacitance, output capacitance, dv/dt rating, thermal impedance of junction to case, case mechanics are all considered.

The amplifier is designed always to be working into an inductive load to minimize the switching loss and dv/dt.



$$f(x) = \frac{4}{\pi} \sum_{n=1,3,5,...}^{\infty} \frac{1}{n} \sin\left(\frac{n\pi x}{L}\right).$$

Square wave produced by Class D has a fundamental and many odd harmonics





Amplifier efficiency is affected by 2 factors:

- FET on resistance (i^2R_{DSon})
- Switching loss $(1/2CV^2F)$

R_{DSon} can be minimized by choosing a high current FET

Switching loss can be minimized by reducing the voltage across the FET during turn on – this is accomplished by an inductive load also known as zero voltage switching (ZVS)











Design sequence (iterative)

- 1) FET selection determines B+ (BVdss x derating)
- 2) Modulation depth selection determines PAV {PAV=B+/(mod+1)}
- 3) TX TPO and # of RF modules determine power per module
- 4) System impedance, # of RF modules and combiner turns ratio determines filter input impedance and PA impedance
- 5) Filter input impedance determines filter component values

Power = Voltage²/resistance

PA testing and analysis to ensure PA power is reliable



Typical values for NX50

- 1) B+ = 400 VDC
- 2) PAV = 163 VDC
- 3) MOD Depth = 145%
- 4) # of RF modules = 20
- 5) Filter input Impedance = 4.17 Ω <25° or 4.60 Ω //+j9.87 Ω
- 6) Primary Turns = 6
- 7) PA impedance = 8.28 Ω //+j17.77 Ω
- 8) PA Power = $146 V rms^2/8.28 \Omega = 2574 watts^*$
- 9) 2574 watts x 20= 50 kW

*don't forget square wave to sine conversion (4/ π) and peak to RMS (1/sqrt2)



Engineering has designed a spreadsheet to execute the required calculations efficiently

			Gene	eralize	ed Har	monie	c Filte	r Netv	vork -	Shur	t Not	ch								
Peak Mod	PA(V)@ FP	Phase Angle	Veffective	Pout	Nominal FET Resistance (mOhm)	Rfet*2	Pfet	Rac	Pload	Efficiency	XI	T otal Rac @ 20 degrees	Primary Turns (Cube)	Secondary T urns (Combiner)	Number of Modules	Output Impedance				
145.00%	163.27	25.00	133.22	2500.00	50	0.15	55.18	6.80	2500.00	0.98	3.17	7.50	6	1	20	50				
Frequency		Inn	ut Impode	ance per Input		Inpute	Power	r per Input Total Power (-14/)										
kHz rad/s		R	+JX	+JX mag		n	RMS	Peak	RMS	Peak	Carrier									
1710	1.1E+07	3.78	1.76	4.2	25.0	1	75000	300125	75	300.125	50									
Resistances		Elementary 90 Degi			90 Degree	T Section	Impedanc	es	0		Churt Natah		-	Adjusted Centre F		Resistance				
Resis	Contro	Phase	74		C (nE)	70	Second I	C (nE)	Series C	apacitor	Snunt C2p (pE)	Notch		13.739	aalatana	Adjusta	ont Foot	~~		
2 70	12 7	0.164	7 20	L (UH)	12.02	26.2	L (UH)	2 (NF)	CS (Ω)	2 70	2 16	Ln (uH)			esistanci	e Adjustn	nent Fact	or		
3.70	13.7	0.104	1.20	0.07	12.92	20.2	2.44	3.00	30	2.19	3.10	0.303		Note: de	croaso if	moasuro	d canacit	anco is > 10	0% by 0 01 :	at a time until
		Ideal Net	work (90	Degree T	Sections)									all induc	tors are i	calculater	d and the	n decrease	by an additi	onal 0.03
Са	pacitors (nF)	Inductors (uH)											Confirm Voltage is less than 66%. Current is less than 70% and Power					and Power is	
C1	C2	Cs	L1 (ttl)	L1 (per)	L2	L3	Ln							less than	1 66% of 1	rated for a	all capaci	tors		
12.92	3.16	3.102	0.834	0.83	3.110	5.23	0.3049													
					Stress Lev	rels - Ideal	Network		N					No	ormalized Stress Levels					
Po	ower (kVA	R)	Current (rms A					ips)			Voltage (peak)			Power (kVAR per nF)			Current (rms Amps per nF)			
182	205	CS 45	C1 150	C2 83	CS 30	140.0	L1 total	L2 74	L3 30	Ln 83	C1 3242	6050	2287	C1 14.1	65.0	14.5	C1 12.3	26.4	12.5	
102	205	45	155	05		140.5	141	/4	- 55	00	3242	0333	5207	14.1	03.0	14.5	12.0	20.4	12.5	
		Redu	ced Q Ne	work					Increa	sed Q Net	work for F	irst T Se	ction							
Measure	d Capacita	ance (nF)) New Required Inductance			e (uH)		Inductar	nce (uH)	C1		C1 S	tress							
C1	C2	Cs	L1 (ttl)	L2	L3	Ln		L1 (ttl)	L2	nF	kVAR	kVAR/nF	Irms	Vpk						
12.00	3.00	3.00	0.75	2.36	3.93	0.32		1.03	3.38	12.00	256.4	21.365	181.81	3989.3						
93%	90%	9170	69%	/0%	/3%	105%	1	123%	109%	93%	141%	151%	114%	123%						
					Stress Le	vels - Red	uced Q Ne	twork						Norr	nalized S	tress Lev	els - Red	uced Q Net	work	
Po	ower (kVA	R)	R) Current (nt (rms Amps)				Voltage (peak)			r (kVAR p	er nF)	Current	t (rms Amps		
C1	C2	Cs	C1	C2	Cs	L1 per	L1 total	L2	L3	Ln	C1	C2	Cs	C1	C2	Cs	C1	C2	Cs	
136	161	47	133	72	39	141	141	74	39	72	2910	6316	3399	11.4	53.6	15.5	11.1	24.0	12.9	
75%	78%	103%	83%	86%	100%	100%	100%	100%	100%	86%	90%	91%	103%	81%	82%	107%	90%	91%	103%	
oaded Q	of L Secti	ons		Phase of	L Sections	5		+JX F	hase											
[1-in	T1-out	T2-in	T2-out	T1-in	T1-out	T2-in	T2-out				C1	C2	Cs	L1	L2	L3	Ln		Total Watts	427
1.65	0.16	1.68	0.22	59	9	59	13	2	5		136	161	47	-97	138	63	18	kVar	Efficiency	99.43%
											1200	1200	1200	1000	1000	1000	500	Q		
Total Phase Delay (With Input Te					put Term):	165				114	134	39	-97	138	63	36	Watts			
				Total Cali	bration Pha	ase Delay:	140													
NG200, Zir	1:13.4 + J3 uires serio:	.7, 300 kW	average, 1	110 kW pe	ak except for C	`c														
ule. neq	unes series	pairs ior C	∠, ∪arii10t	use 0.045	eventing C	-3														



FET chosen for NX



APT50M50JFLL

500V 71A 0.050Ω

POWER MOS 7[®] FREDFET

Power MOS 7^{*} is a new generation of low loss, high voltage, N-Channel enhancement mode power MOSFETS. Both conduction and switching losses are addressed with Power MOS 7^{*} by significantly lowering R_{DS(DN)} and Q_g. Power MOS 7^{*} combines lower conduction and switching losses along with exceptionally fast switching speeds inherent with APT's patented metal gate structure.

- Lower Input Capacitance
- Lower Miller Capacitance
- Lower Gate Charge, Qg
- Increased Power Dissipation
- Easier To Drive
- Popular SOT-227 Package









MAXIMUM RATINGS

All Ratings: T_C = 25°C unless otherwise specified.

Symbol	Parameter	APT50M50JLL	UNIT			
V _{DSS}	Drain-Source Voltage	500	Volts			
Ь	Continuous Drain Current @ T _C = 25°C	71	Amos			
Чрм	Pulsed Drain Current	284	bo			
V _{GS}	Gate-Source Voltage Continuous	±30	Volts			
V _{GSM}	Gate-Source Voltage Transient	±40				
P	Total Power Dissipation @ T _C = 25°C	595	Watts			
	Linear Derating Factor	4.76	W/°C			
T_,T _{STG}	Operating and Storage Junction Temperature Range	-55 to 150	°c			
ΤL	Lead Temperature: 0.063" from Case for 10 Sec.	300				
I _{AR}	Avalanche Current (Repetitive and Non-Repetitive)	71	Amps			
EAR	Repetitive Avalanche Energy 🛈	50	ml			
EAS	Single Pulse Avalanche Energy ⁽³⁾	3200				



STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	ТҮР	MAX	UNIT
BVDSS	Drain-Source Breakdown Voltage ($V_{GS} = 0V, I_D = 250\mu A$)	500			Volts
R _{DS(on)}	Drain-Source On-State Resistance $(V_{GS} = 10V, 35.5A)$			0.050	Ohms
I _{DSS}	Zero Gate Voltage Drain Current (V _{DS} = 500V, V _{GS} = 0V)			100	μΑ
	Zero Gate Voltage Drain Current ($V_{DS} = 400V, V_{GS} = 0V, T_{C} = 125^{\circ}C$)			500	
GSS	Gate-Source Leakage Current ($V_{GS} = \pm 30V$, $V_{DS} = 0V$)			±100	nA
V _{GS(th)}	Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = 5mA)	3		5	Volts

CAUTION: These Devices are Sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

APT Website - http://www.advancedpower.com



Harmonic filter needs to impedance match the antenna to the amplifier to achieve designed power. (4.17 Ω <25° to 50 Ω)

The harmonic filter needs to attenuate harmonics produced in the amplifiers.

The harmonic filter needs to provide isolation from external energy which could damage the amplifiers.





We can know Q because: $Q^2 + 1 = \frac{R_P}{R_S}$ or $Q = \sqrt{\frac{R_P}{R_S}} - 1$

L Networks are used to step up or step down impedance





making digital broadcasting work

T networks are back to back L networks





Harmonic filter uses a double Tee with 3rd notch design to reduce harmonics and impedance match the RF amp to the antenna. Double Tee has the advantage of :

- keeping impedance matched as shunt C drifts with temperature
- Wide bandwidth
- Good attenuation

A series capacitor and shunt coil provide static and low freq transient protection as well as transient suppressor device.



Combiner

The combiner needs to efficiently add the RF modules powers while providing isolation between inputs.

Combiners can be categorized as those with balancing resistors and those without.

Number of inputs needs to be greater than 4 for combiners without balancing resistors in ordered for reasonable isolation under failure.



Combiner

AM, for several generations, has used combiners without balancing resistors.

AM Combiners have been both parallel (60°) and series. Ampfet , NX = series ND, XL, XR, NA= parallel

Series combining is broadband, less expensive, and uses a smaller footprint



Combiner/Harmonic Filter



Frequency Agile: Harmonic Filter Re-Tune in a Few Hours



Pulse Width Modulator



- This circuit illustrates the simple switched modulator principle. It applies a fixed DC supply voltage B+ through a series switch to a low pass filter.
- The switch is opened and closed at a fixed frequency of approximately 70 kHz producing a square wave with a peak value of B+ at the filter input.
- The filter rejects the 70 kHz signal and produces a dc voltage at its output equal to the average value of the square wave
 - Example: one half of B+ for a 50/50 duty cycle.
- If the duty cycle is slowly varied, the DC output voltage may be adjusted from 0 to B+.



Origins of PWM Generator



- 70 kHz multi-vibrator can be passed to an integrator to produce the required saw-tooth waveform.
- If an audio modulating signal is superimposed on the control voltage, then the width of the pulses in the PWM control signal will vary accordingly.
- Waveforms depicting this process are shown on the next slide.
- It is important to understand that both the RF output level and the modulation information is digitally encoded into the PWM control signal's pulse width while its repetition frequency and amplitude remain constant.



Sulput Signal.

Example input signal

Modulation Design

PWM Generator Waveforms

These waveforms illustrate how the width of the PWM pulses increase in response to a

Voltage

- These waveforms illustrate how the width of the PWM pulses increase in response to a rising control waveform input.
- Note the constant amplitude and repetition frequency of the PWM signal.
- The saw-tooth must have a very stable DC reference level and a very linear slope to ensure high fidelity of the transmitter's modulated output signal.



- PWM signals generated for Carrier only – no audio applied
- PDM signals generated for carrier with audio applied





- PWM signals generated for Carrier only – no audio applied
- PDM signals generated for carrier with audio applied





Digital Modulation Technology

Separate power processing stages for Envelope Modulation and RF Amplification are Employed. This approach enjoys the following benefits:

- •Optimal RF Transistor switching is maintained at all modulation levels. This cannot be achieved when the RF transistors must both convert DC to RF and vary the RF envelope.
- •Digitally controlled RF Transistor switching has nearly eliminated switching loss across the AM band
- •Allows for very high current capability transistors to reduce conduction loss
- •Results in ultra high efficiency RF amplifier (up to 98% at 1710 kHz)
- •RF Amplifier DC Supply can be shut down during transient events/VSWR to further improve robustness

•All amplifiers see the same load at all power and modulation levels

The 9 Modulation phases are separately synthesized digitally at 317 MSPS in the exciter FPGA. This results in very low quantization noise.

Each Modulator phase samples the desired envelope at a rate of over 300 kHz.

The 9 Phase process samples the envelope at over 2.7 million samples per second. This rate does not change with frequency.

Distortion due to the modulation process is essentially eliminated.

Reduced switching harmonic content allows for a very low Q modulation filter.

9 Phase Digital Modulation





• Amplifier Design





- Exciter design has advanced greatly from early TTL and discretes to a powerful DSP and FPGA.
- The 2 signals being generated have not changed: RF drive (carrier freq) and Mod Drive (PDM)
- With the DSP, the exciter can now compensate for many of the distortions in the amplifiers and modulators.
- Modulator pinch-off, modulator filter roll-off and RF amplifier incidental phase modulation are all corrected.



"The NX Series of AM transmitters are the first high power AM transmitters to be provided with Dynamic Pre-correction"

- Corrects primary forms of distortion
- Applies to analog + digital broadcasting
- More Linear Clean Spectrum
- Adaptive envelope equalization
- Adaptive AM-AM correction
- Adaptive AM-PM correction





Exciter



Figure 2.2: Block Diagram - FPGA





Pre-Correction Principle



An amplifier characteristic g(x)may be corrected for with a complementary characteristic h(x)such that g(h(x)) = Gx

For this to be true, $G h(x) = g^{-1}(x)$





The FPGA has three correction sections in the forward path:

- Envelope equalization: Corrects for filtering effects in the modulator (envelope magnitude and phase response versus frequency)
- AM/AM Correction: Corrects for amplitude error in the modulator due to capacitive effects in the modulator FET. (Essentially AM distortion)
- AM/PM Correction: Corrects for phase error in the RF amplifier due to capacitive effects in the RF FET. (IQM or IPM effects)

Additionally, it will be possible to correct for linear effects in the AM antenna system using a filter in the DSP





NX Modulator Response



making digital broadcasting work

AUI Screen EQ Frequency Response









AUI Screen EQ Filter Delay





No visible distortion in the trough with AM to AM correction





AUI Screen AM-AM Correction





Nearly total elimination of distortion at 25% modulation (Distortion approx. 0.05%)





AUI Screen PM-AM Correction





The AC power from the grid must be rectified so that it can be switched at the desired carrier frequency. AC/DC power conversions has two design possibilities:

- 50/60 Hz rectification 'big iron'
- Switching power supplies

In a nutshell the 'big iron' is very reliable and has excellent \$/W at high power (>10 kW)

Switching power supplies offer higher power density (W/in³), lower weight and higher redundancy



Regulations regarding the AM noise on the output RF signal would force the low pass filter following the rectifiers to be excessive.

Nautel patented a 'lines volt compensation' technique early on in its solid state designs that is continued to be used today.



Power supply design greatly affects the performance of the transmitter within the user's environment.

Big iron power supplies typically use SCR's for soft start and regulation but have power factor levels at approx. 0.93.



When running from generator, the transmitter's regulation circuits can make the load appear as a negative resistance causing instability in the generator's operation.

Also high power rectifiers can cause 'line notching' which drastically reduces the available power from the generator.







Circuit Board Design

Circuit board creation represents a significant portion of the total transmitter design effort.

Circuit boards typically use copper cladded epoxy resin (FR-4) but sometimes employ high quality materials (ie. Teflon) depending on the application.

FR-4 can operate at approx. 90 C before discolouration and delamination.

The copper cladding is quantified in 'ounces' with each ounce resulting in 0.0014" thk of copper cladding.



Circuit Board Design

Nautel has strict guidelines for the current that a PWB conductor may carry versus the ounces of copper.

In high voltage applications, there are rules on creepage and clearance distances that must be followed for maximum reliability.

Nautel has an internal 100 point checklist that every PWB must pass before being manufactured.





Transmitters employs multiple parallel DC cooling fans which provide:

- Redundancy
- High efficiency
- Not sync'd to AC line frequency



Protection

Transmitter's control function provides protection such as:

- SWR protection techniques (cutback, foldback, shutback)
- Thermal protection fan tach, heatsink monitor
- Over current protection
- Over modulation protection



Thank You





